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Vishay Siliconix

THERMAL RESISTANCE RATINGS							
PARAMETER	SYMBOL	TYP.	MAX.	UNIT			
Maximum junction-to-ambient	R _{thJA}	=	65	°C/W			
Maximum junction-to-case (drain)	R_{thJC}	-	3.6	C/VV			

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static						L	ı
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		600	-	-	V
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$	Reference to 25 °C, I _D = 1 mA		-	0.68	-	V/°C
Gate-source threshold Voltage (N)	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$		2.0	-	4.0	V
Gate-source leakage	I _{GSS}	V _{GS} = ± 20 V		-	-	± 100	nA
		$V_{GS} = \pm 30 \text{ V}$		-	-	± 1	μΑ
Zero gate voltage drain current	I _{DSS}	V _{DS} = 600 V, V _{GS} = 0 V		-	-	1	
		V _{DS} = 480 V, V _{GS} = 0 V, T _J = 125 °C		-	-	10	μA
Drain-source on-state resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 11 A	-	0.155	0.180	Ω
Forward transconductance	9 _{fs}	V _{DS} = 8 V, I _D = 11 A		-	16	-	S
Dynamic		•		•	•		
Input capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 100 V, f = 1 MHz		-	1757		pF
Output capacitance	C _{oss}			-	74	-	
Reverse transfer capacitance	C _{rss}			-	6	-	
Effective output capacitance, energy related ^a	C _{o(er)}	V _{DS} = 0 V to 480 V, V _{GS} = 0 V		-	48	-	
Effective output capacitance, time related ^b	$C_{o(tr)}$			-	257	-	
Total gate charge	Qg	V _{GS} = 10 V		-	41	82	
Gate-source charge	Q _{gs}		-	10	-	nC	
Gate-drain charge	Q _{gd}				13		-
Turn-on delay time	t _{d(on)}	$V_{DD} = 480 \text{ V}, I_{D} = 11 \text{ A}, V_{GS} = 10 \text{ V}, R_{g} = 9.1 \Omega$		-	27	54	- ns
Rise time	t _r			-	24	48	
Turn-off delay time	t _{d(off)}			-	86	172	
Fall time	t _f			-	28	56	
Gate input resistance	R _g	f = 1 MHz, open drain		3.6	7.2	14.4	Ω
Drain-Source Body Diode Characteristic	es						
Continuous source-drain diode current	I _S	MOSFET symbol showing the integral reverse p - n junction diode		-	-	21	
Pulsed diode forward current	I _{SM}			-	-	48	- A
Diode forward voltage	V _{SD}	T _J = 25 °C, I _S = 11 A, V _{GS} = 0 V		-	-	1.2	V
Reverse recovery time	t _{rr}	$T_J = 25 \text{ °C}, I_F = I_S = 11 \text{ A},$ $di/dt = 100 \text{ A/µs}, V_R = 400 \text{ V}$		-	285	570	ns
Reverse recovery charge	Q _{rr}			-	4.1	8.2	μC
Reverse recovery current	I _{RRM}			-	27	-	A

Notes

- a. $C_{oss(er)}$ is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS} b. $C_{oss(tr)}$ is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS}



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

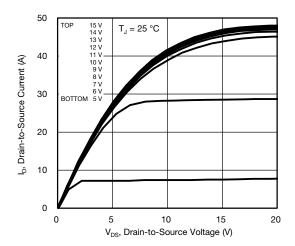


Fig. 1 - Typical Output Characteristics

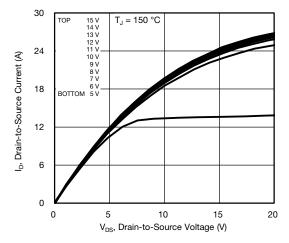


Fig. 2 - Typical Output Characteristics

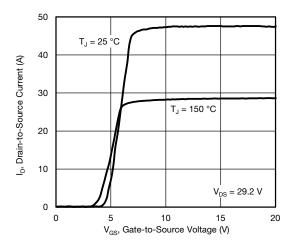


Fig. 3 - Typical Transfer Characteristics

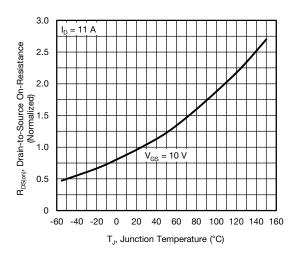


Fig. 4 - Normalized On-Resistance vs. Temperature

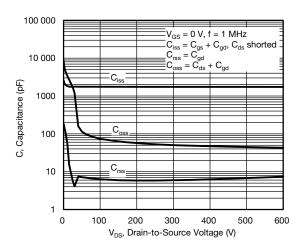


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

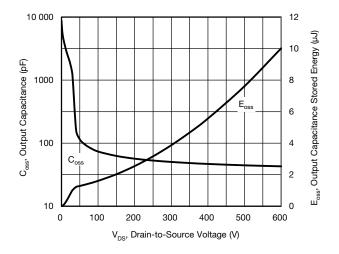


Fig. 6 - C_{oss} and E_{oss} vs. V_{DS}



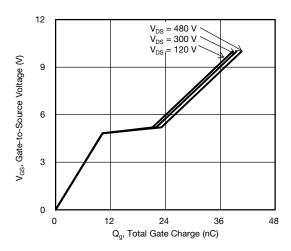


Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage

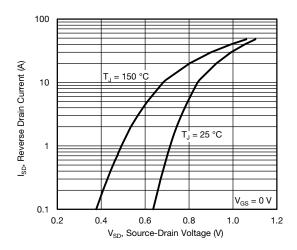


Fig. 8 - Typical Source-Drain Diode Forward Voltage

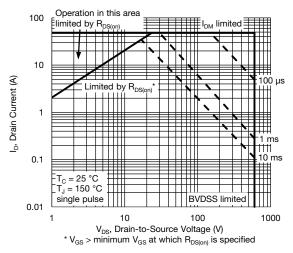


Fig. 9 - Maximum Safe Operating Area

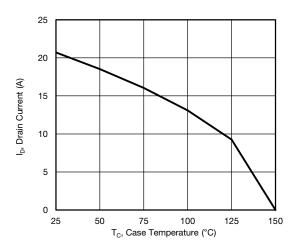


Fig. 10 - Maximum Drain Current vs. Case Temperature

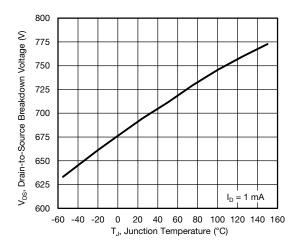


Fig. 11 - Temperature vs. Drain-to-Source Voltage



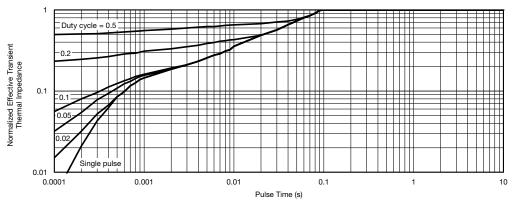


Fig. 12 - Normalized Thermal Transient Impedance, Junction-to-Case

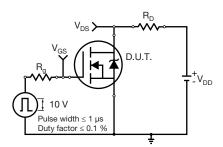


Fig. 13 - Switching Time Test Circuit

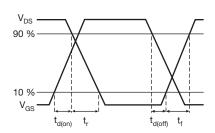


Fig. 14 - Switching Time Waveforms

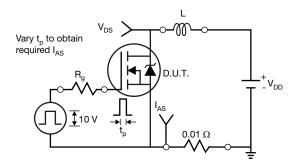


Fig. 15 - Unclamped Inductive Test Circuit

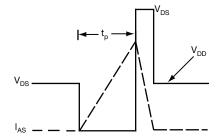


Fig. 16 - Unclamped Inductive Waveforms

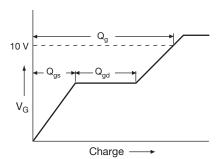


Fig. 17 - Basic Gate Charge Waveform

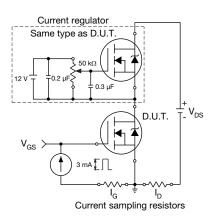
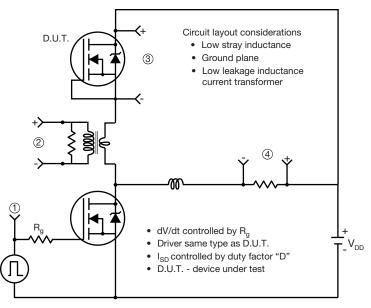


Fig. 18 - Gate Charge Test Circuit



Peak Diode Recovery dV/dt Test Circuit



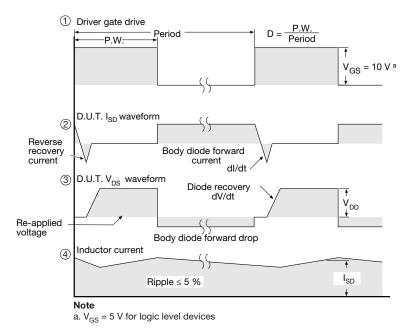


Fig. 19 - For N-Channel

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